



SANYO Semiconductors

DATA SHEET

An ON Semiconductor Company

P-Channel Silicon MOSFET

CPH6347 — General-Purpose Switching Device Applications

Features

- 1.8V drive
- Halogen free compliance
- Protection diode in

Specifications

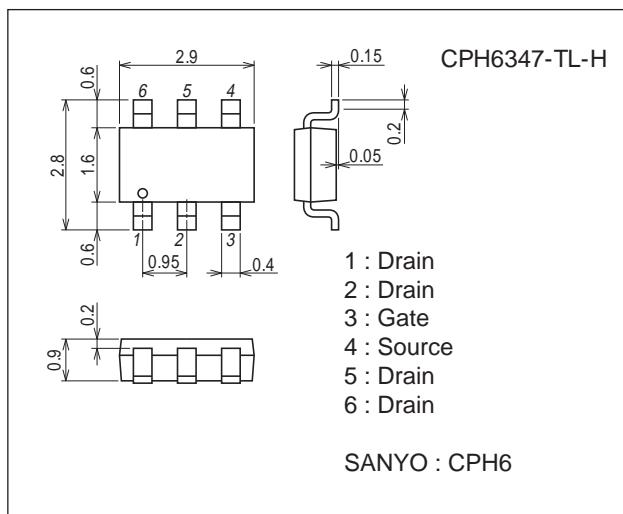
Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		-20	V
Gate-to-Source Voltage	V _{GSS}		±12	V
Drain Current (DC)	I _D		-6	A
Drain Current (Pulse)	I _{DP}	PW≤10μs, duty cycle≤1%	-24	A
Allowable Power Dissipation	P _D	When mounted on ceramic substrate (900mm ² ×0.8mm)	1.6	W
Channel Temperature	T _{ch}		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Package Dimensions

unit : mm (typ)

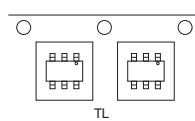
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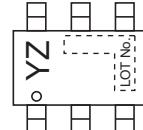
Product & Package Information

- Package : CPH6
- JEITA, JEDEC : SC-74, SOT-26, SOT-457
- Minimum Packing Quantity : 3,000 pcs./reel

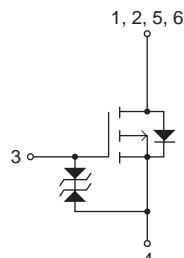
Packing Type: TL



Marking

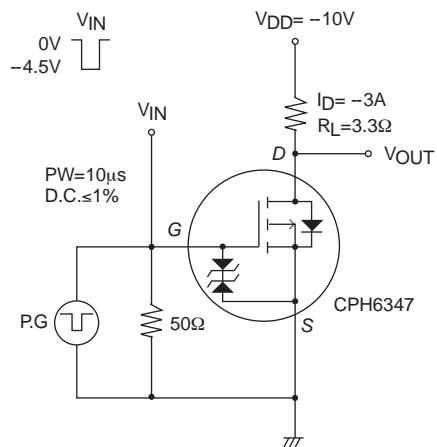


Electrical Connection

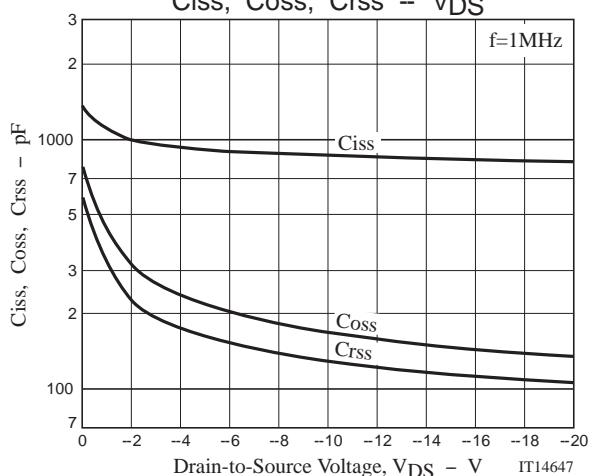
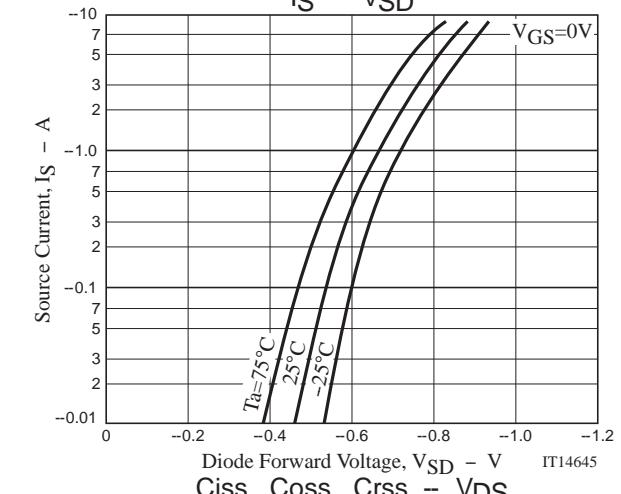
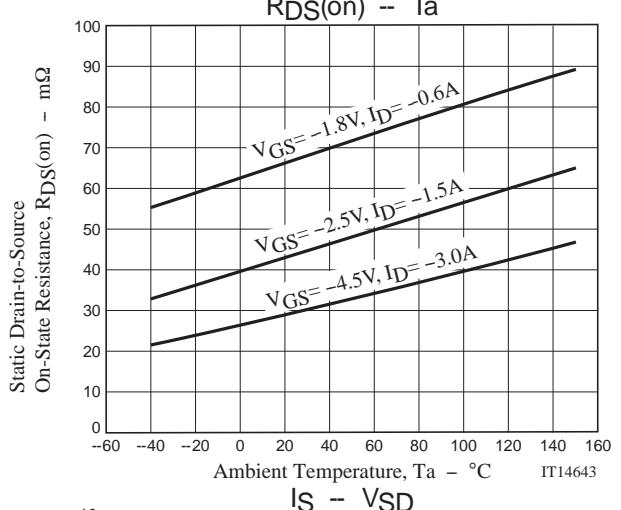
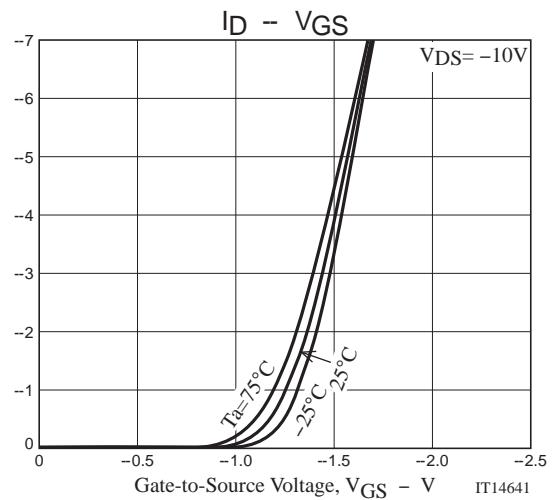
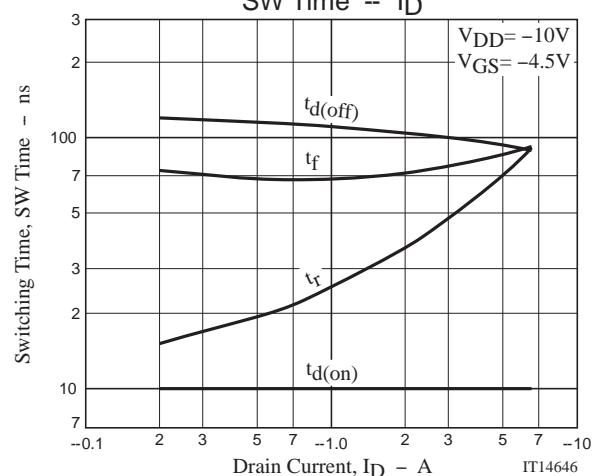
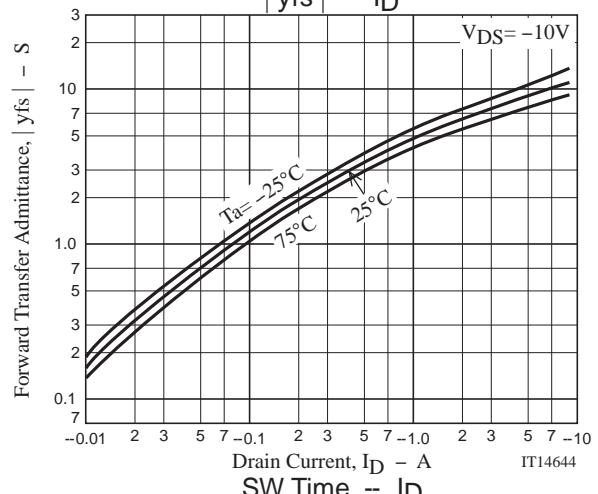
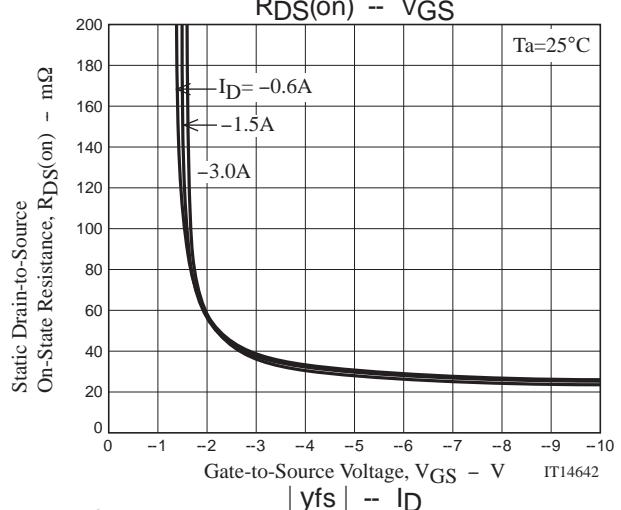
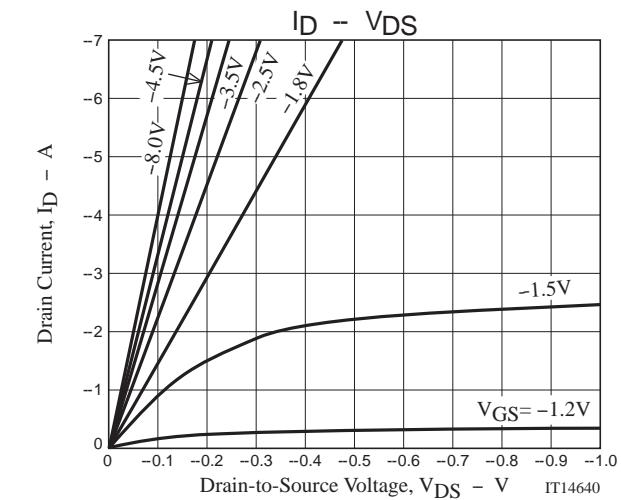


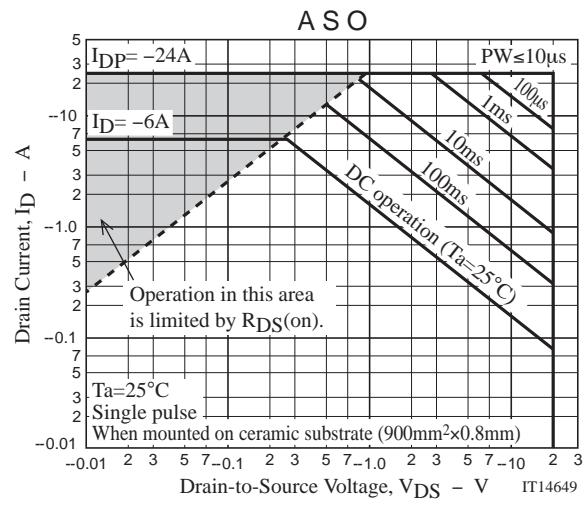
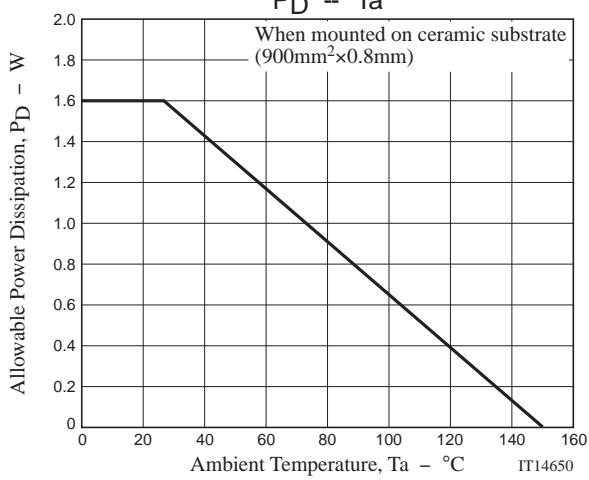
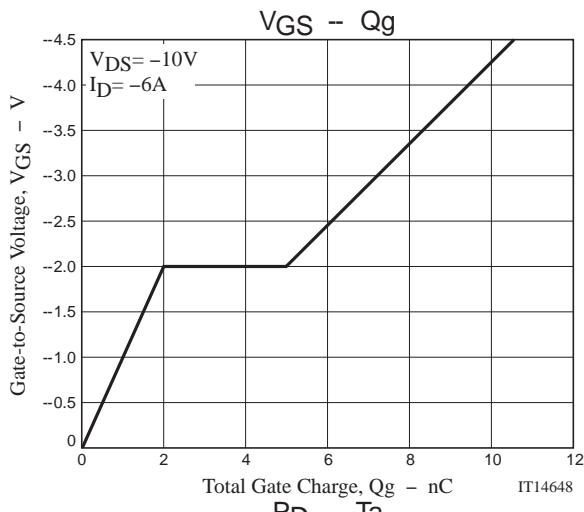
Electrical Characteristics at $T_a=25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	$V_{(\text{BR})\text{DSS}}$	$I_D=-1\text{mA}, V_{GS}=0\text{V}$	-20			V
Zero-Gate Voltage Drain Current	I_{DSS}	$V_{DS}=-20\text{V}, V_{GS}=0\text{V}$			-1	μA
Gate-to-Source Leakage Current	I_{GSS}	$V_{GS}=\pm 8\text{V}, V_{DS}=0\text{V}$			± 10	μA
Cutoff Voltage	$V_{GS(\text{off})}$	$V_{DS}=-10\text{V}, I_D=-1\text{mA}$	-0.4		-1.4	V
Forward Transfer Admittance	$ y_{fs} $	$V_{DS}=-10\text{V}, I_D=-3\text{A}$	4.3	7.3		S
Static Drain-to-Source On-State Resistance	$R_{DS(\text{on})1}$	$I_D=-3\text{A}, V_{GS}=-4.5\text{V}$		30	39	$\text{m}\Omega$
	$R_{DS(\text{on})2}$	$I_D=-1.5\text{A}, V_{GS}=-2.5\text{V}$		44	66	$\text{m}\Omega$
	$R_{DS(\text{on})3}$	$I_D=-0.6\text{A}, V_{GS}=-1.8\text{V}$		68	102	$\text{m}\Omega$
Input Capacitance	C_{iss}	$V_{DS}=-10\text{V}, f=1\text{MHz}$		860		pF
Output Capacitance	C_{oss}			170		pF
Reverse Transfer Capacitance	C_{rss}			130		pF
Turn-ON Delay Time	$t_{\text{d}(\text{on})}$	See specified Test Circuit.		10		ns
Rise Time	t_r			48		ns
Turn-OFF Delay Time	$t_{\text{d}(\text{off})}$			100		ns
Fall Time	t_f			78		ns
Total Gate Charge	Q_g	$V_{DS}=-10\text{V}, V_{GS}=-4.5\text{V}, I_D=-6\text{A}$		10.5		nC
Gate-to-Source Charge	Q_{gs}			2.0		nC
Gate-to-Drain "Miller" Charge	Q_{gd}			3.0		nC
Diode Forward Voltage	V_{SD}	$I_S=-6\text{A}, V_{GS}=0\text{V}$		-0.82	-1.5	V

Switching Time Test Circuit**Ordering Information**

Device	Package	Shipping	memo
CPH6347-TL-H	CPH6	3,000pcs./reel	Pb Free and Halogen Free



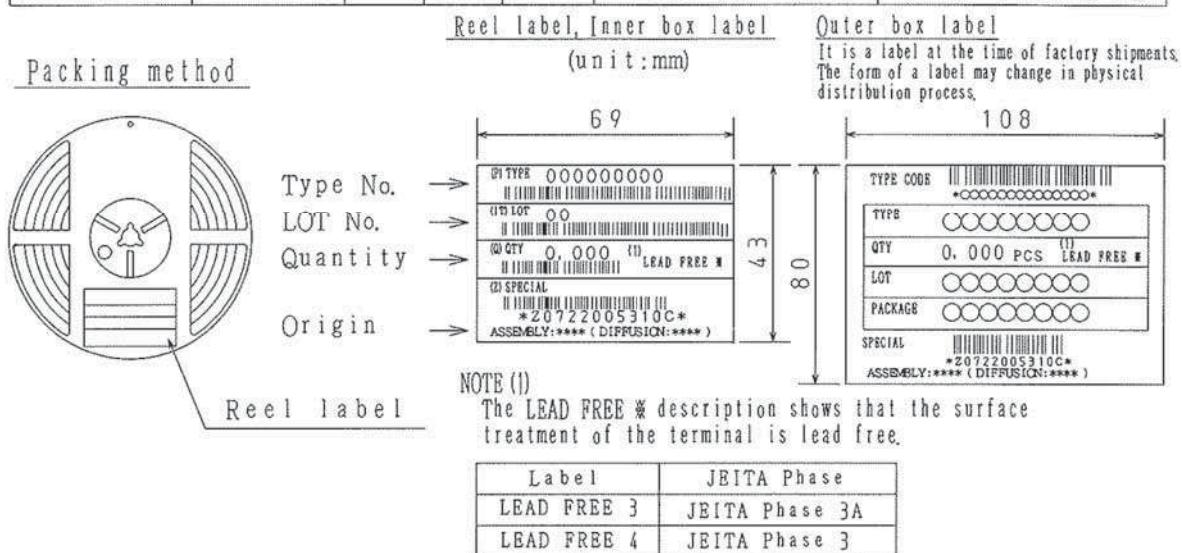


Embossed Taping Specification

CPH6347-TL-H

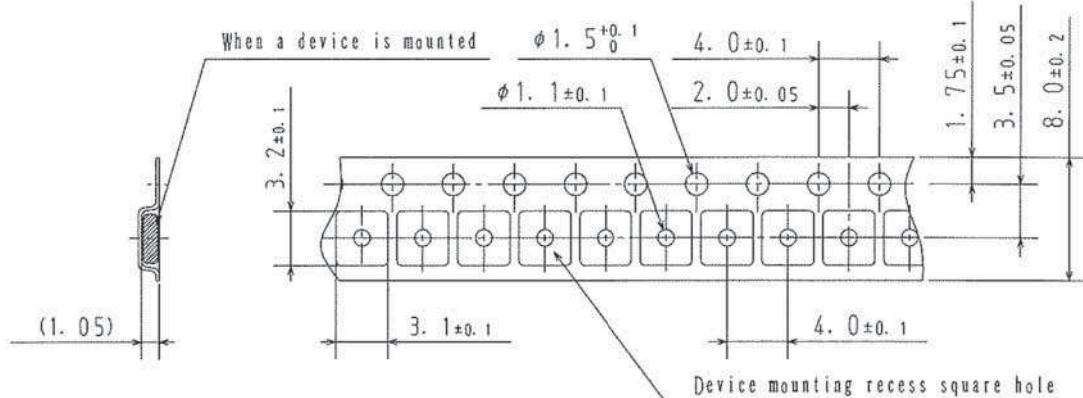
1. Packing Format

Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
CPH6	CPH6	3,000	15,000	90,000	5 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

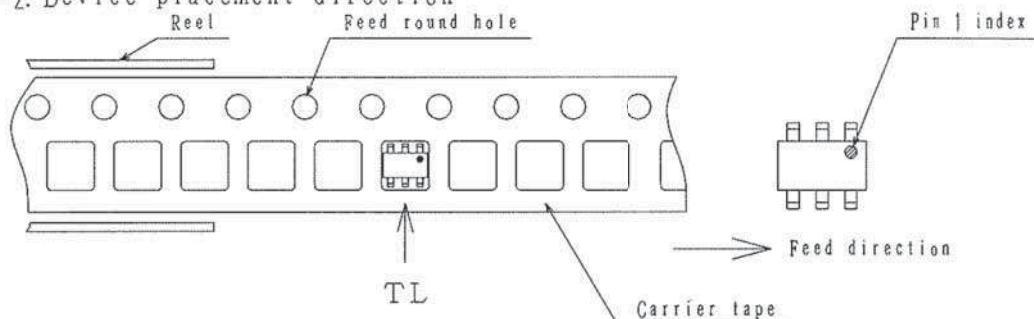


2. Taping configuration

2-1. Carrier tape size (unit:mm)



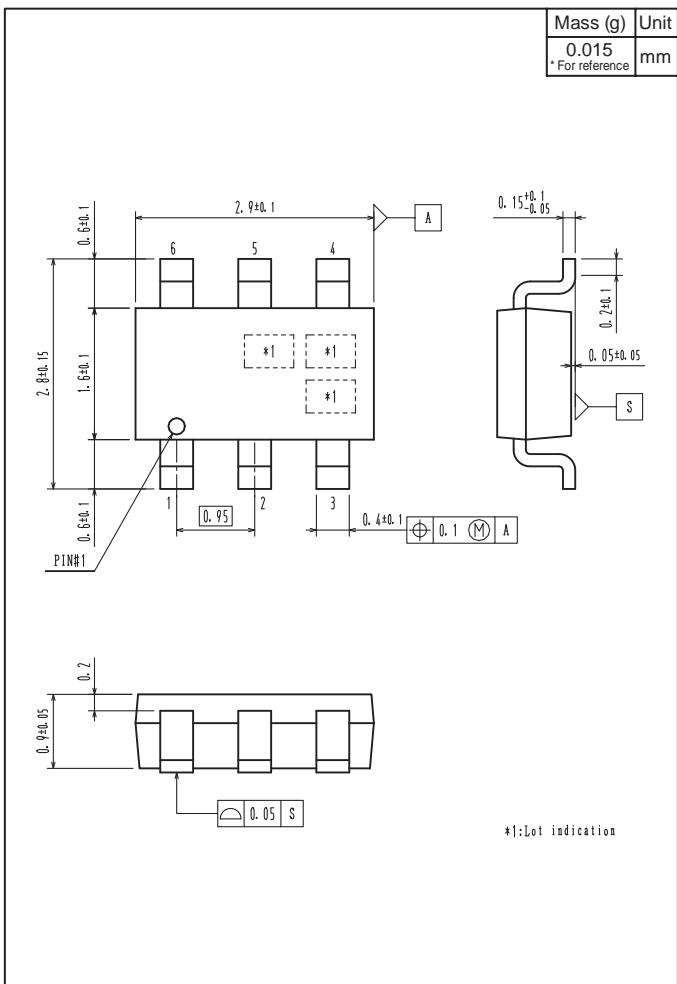
2-2. Device placement direction



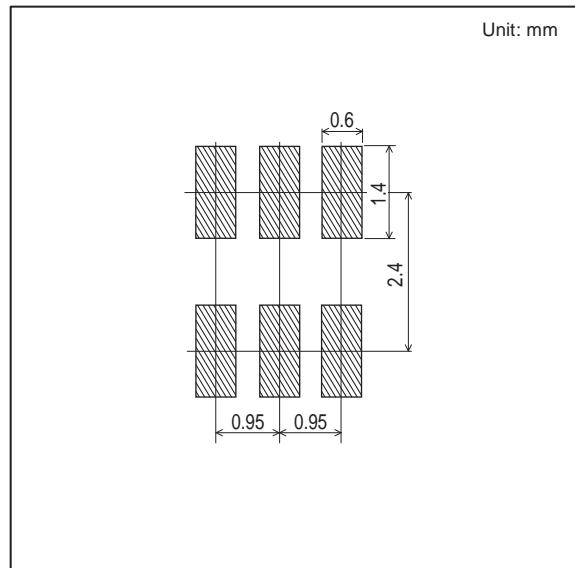
Those with pin 1 index on the feed hole side.....TL

Outline Drawing

CPH6347-TL-H



Land Pattern Example



Note on usage : Since the CPH6347 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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